

2SC2610

Silicon NPN Triple Diffused

REJ03G0700-0200
(Previous ADE-208-1068)
Rev.2.00
Aug.10.2005

Application

- High voltage amplifier
- TV Video output

Outline

RENESAS Package code: PRSS0003DC-A
(Package name: TO-92 Mod)



1. Emitter
2. Collector
3. Base

Absolute Maximum Ratings

(Ta = 25°C)

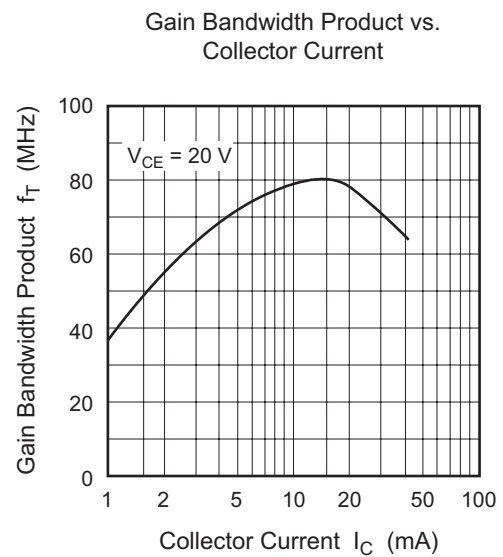
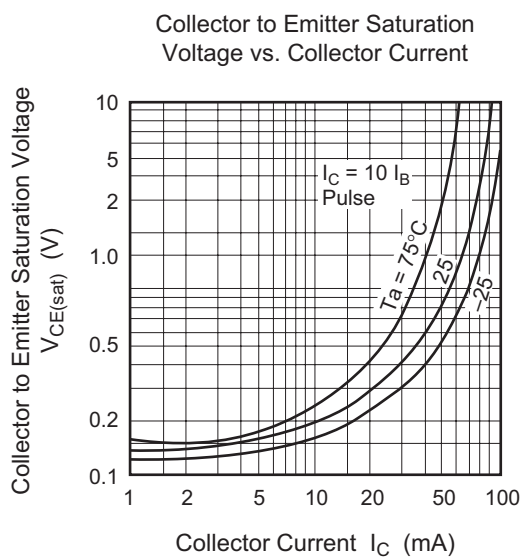
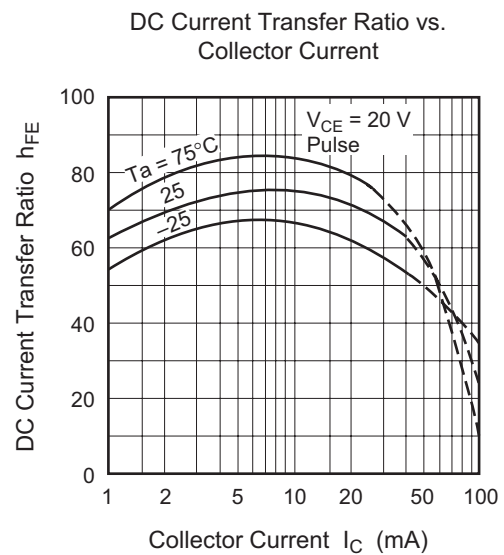
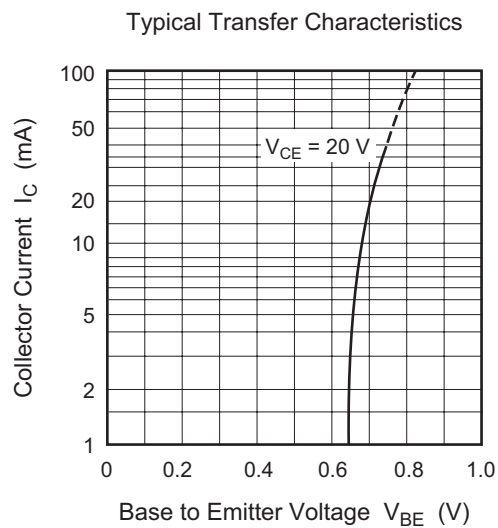
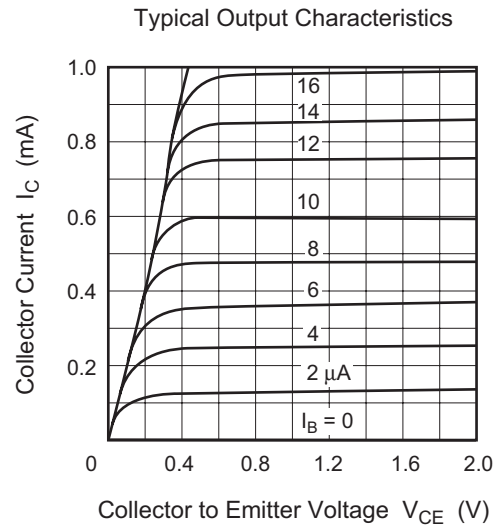
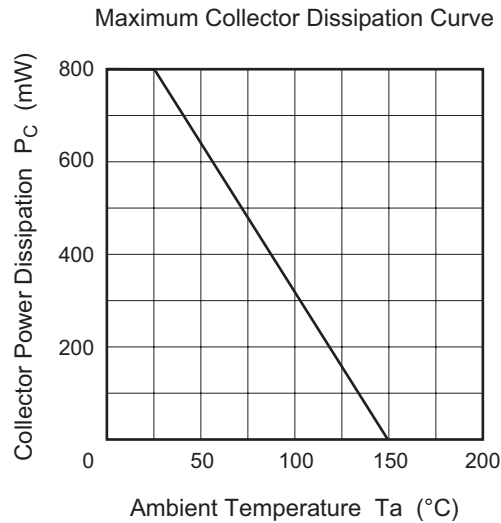
Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	300	V
Collector to emitter voltage	V_{CEO}	300	V
Emitter to base voltage	V_{EBO}	5	V
Collector current	I_C	100	mA
Collector power dissipation	P_C	800	mW
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-55 to +150	°C

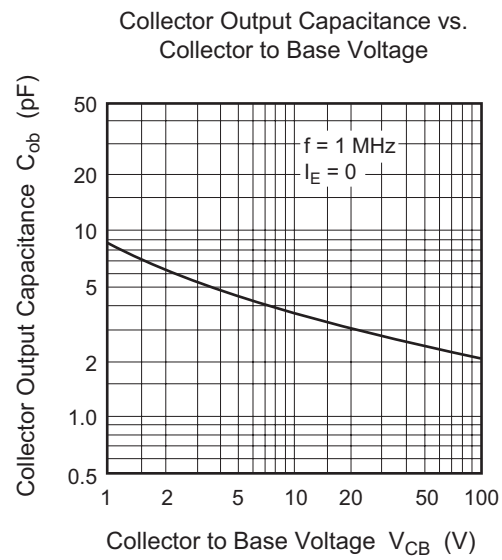
Electrical Characteristics

(Ta = 25°C)

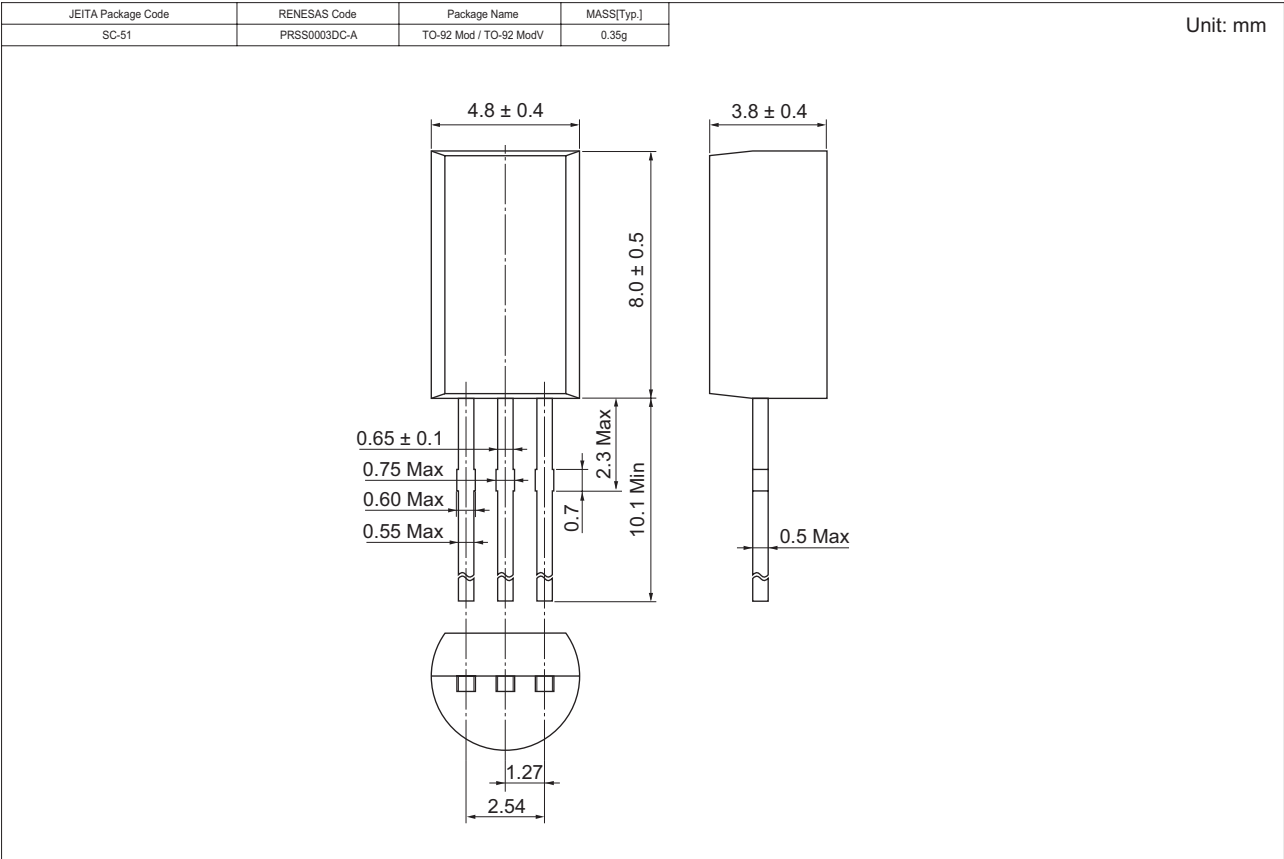
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	300	—	—	V	$I_C = 10\ \mu A, I_E = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	300	—	—	V	$I_C = 1\ mA, R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	—	—	V	$I_E = 10\ \mu A, I_C = 0$
Collector cutoff current	I_{CEO}	—	—	1.0	μA	$V_{CE} = 250\ V, R_{BE} = \infty$
DC current transfer ratio	h_{FE}	30	—	200		$V_{CE} = 20\ V, I_C = 20\ mA$
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	—	1.5	V	$I_C = 20\ mA, I_B = 2\ mA$
Gain bandwidth product	f_T	50	80	—	MHz	$V_{CE} = 20\ V, I_C = 20\ mA$
Collector output capacitance	C_{ob}	—	—	4.0	pF	$V_{CB} = 20\ V, I_E = 0, f = 1\ MHz$

Main Characteristics





Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SC2610TZ-E	2500	Hold Box, Radial Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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